

Low Noise wideband MMIC VCO is ideal for:



HMC588LC4B

WIDEBAND MMIC VCO w/ BUFFER AMPLIFIER, 8.0 - 12.5 GHz

Features

Wide Tuning Bandwidth Pout: +5 dBm Low SSB Phase Noise: -93 dBc/Hz @100 kHz No External Resonator Needed Single Positive Supply: +5V @ 55 mA RoHS Compliant 4 x 4 mm SMT Package

General Description

The HMC588LC4B is a wideband GaAs InGaP HBT MMIC Voltage Controlled Oscillator which incorporates the resonator, negative resistance device, and varactor diode. Output power and phase noise performance are excellent over temperature due to the oscillator's monolithic construction. The Vtune port accepts an analog tuning voltage from 0 to +13V. The HMC588LC4B VCO operates from a single +5V supply, consumes only 55 mA of current, and is housed in a RoHS compliant SMT package. This wideband VCO uniquely combines the attributes of ultra small size, low phase noise, low power consumption, and wide tuning range.

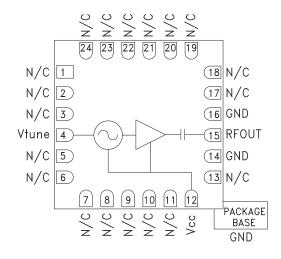
Functional Diagram

Typical Applications

Industrial/Medical Equipment

• Military Radar, EW & ECM

• Test & Measurement Equipment



Electrical Specifications, $T_A = +25^{\circ}$ C, Vcc = +5V

Parameter	Min.	Тур.	Max.	Units
Frequency Range		8.0 - 12.5		
Power Output	2	5		dBm
SSB Phase Noise @ 100 kHz Offset		-93		dBc/Hz
SSB Phase Noise @ 10 kHz Offset		-65		dBc/Hz
Tune Voltage (Vtune)	0		13	V
Supply Current (Icc) (Vcc = +5.0V)	40		75	mA
Tune Port Leakage Current (Vtune = +13V)			10	μA
Output Return Loss		7		dB
2nd Harmonic		-18		dBc
Pulling (into a 2.0:1 VSWR)		4		MHz pp
Pushing @ Vtune= +5V		100		MHz/V
Frequency Drift Rate		0.3		MHz/°C

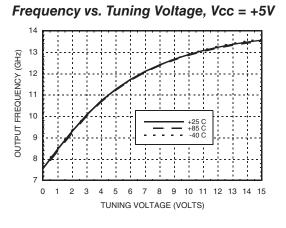
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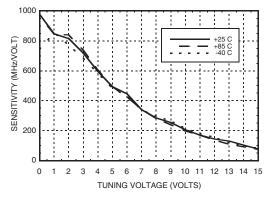
VCOs & PLOs - SMT



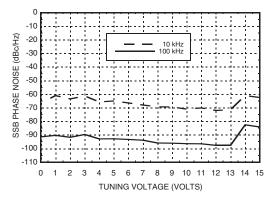
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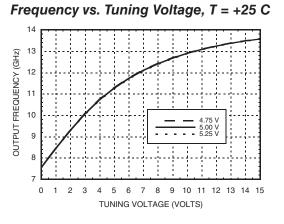


Sensitivity vs. Tuning Voltage, Vcc= +5V

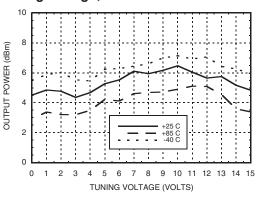


SSB Phase Noise vs. Tuning Voltage

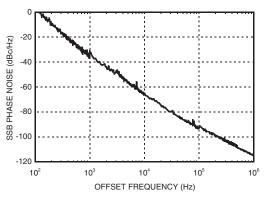




Output Power vs. Tuning Voltage, Vcc= +5V



Typical SSB Phase Noise @ Vtune= +5V





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ROHS V EARTH PRIENDLY

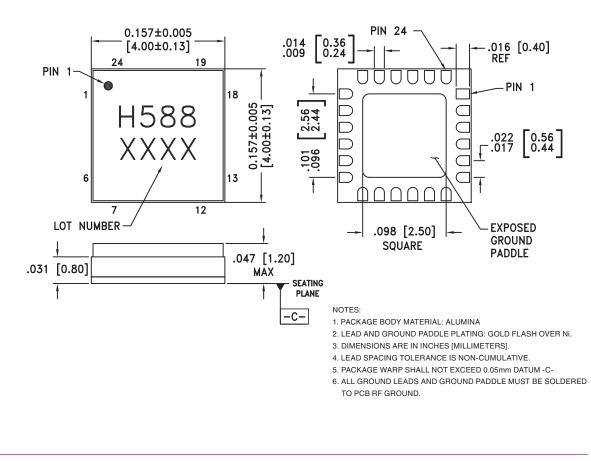
Absolute Maximum Ratings

Vcc	+5.5 Vdc
Vtune	0 to +15V
Junction Temperature	135 °C
Continuous Pdiss (T = 85°C) (derate 10.5 mW/°C above 85°C)	526 mW
Thermal Resistance (junction to ground paddle)	95 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A

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VCOs & PLOs - SMT

Outline Drawing

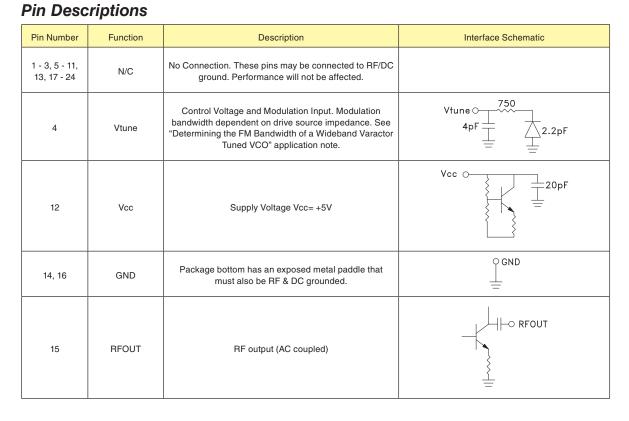


BOTTOM VIEW



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EARTH FRIENDLY



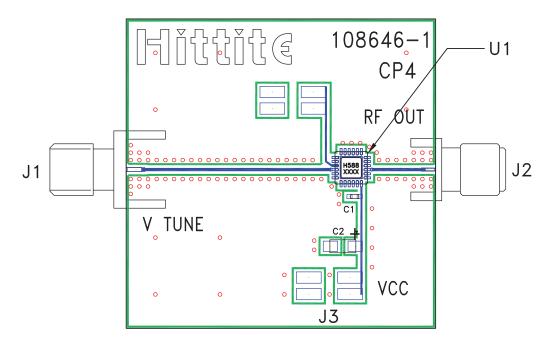
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ROHS V

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Evaluation PCB



List of Materials for Evaluation PCB 108648^[1]

Item	Description
J1	PCB Mount SMA RF Connector, Johnson
J2	PCB Mount SMA Connector, SRI
J3	DC Header
C1	1000 pF Capacitor, 0402 Pkg.
C2	4.7 μF Capacitor, Tantalum
U1	HMC588LC4B VCO
PCB ^[2]	108646 Eval Board

Reference this number when ordering complete evaluation PCB
Circuit Board Material: Rogers 4350

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed ground paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

For price, delivery, and to place orders, please contact Hittite Microwave Corporation: 20 Alpha Road, Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.com

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Notes: